

RELIABILITY REPORT FOR

MAX3183EEUK+T

PLASTIC ENCAPSULATED DEVICES

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MAXIM INTEGRATED

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Approved by				
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Conclusion

The MAX3183EEUK+T successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAX3180E-MAX3183E single RS-232 receivers in a SOT23-5 package are designed for space- and cost-constrained applications requiring minimal RS-232 communications. The receiver inputs are protected to ±15kV using IEC 1000-4-2 Air-Gap Discharge, to ±8kV using IEC 1000-4-2 Contact Discharge, and to ±15kV per the Human Body Model, ensuring compliance with international standards. The devices minimize power and heat dissipation by consuming only 0.5µA supply current from a +3.0V to +5.5V supply, and they guarantee true RS-232 performance up to a 1.5Mbps data rate. The MAX3180E/MAX3182E feature a three-state TTL/CMOS receiver output that is controlled by an active-low EN logic input. The MAX3181E/MAX3183E feature an active-low INVALID output that indicates valid RS-232 signals at the receiver input for applications requiring automatic system wake-up. The MAX3182E/MAX3183E have a noninverting output, while the MAX3180E/MAX3181E have a standard inverting output.



II. Manufacturing Information

A. Description/Function: ±15kV ESD-Protected, 0.5µA, +3V to +5.5V, 1.5Mbps RS-232 Receivers in

SOT23-5

Level 1

B. Process: M5

C. Number of Device Transistors:

D. Fabrication Location: Oregon

E. Assembly Location: Malaysia, Philippines, Thailand

F. Date of Initial Production: July 24, 1999

III. Packaging Information

5-pin SOT23 A. Package Type: B. Lead Frame: Copper

C. Lead Finish: 100% matte Tin D. Die Attach: Conductive E. Bondwire: Au (1 mil dia.) F. Mold Material:

Epoxy with silica filler G. Assembly Diagram: #05-1901-0200 H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity per

JEDEC standard J-STD-020-C

L. Multi Layer Theta Ja:

324.3°C/W J. Single Layer Theta Ja: K. Single Layer Theta Jc: 82°C/W 255.9°C/W

M. Multi Layer Theta Jc: 81°C/W

IV. Die Information

A. Dimensions: 57X38 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: Al/1.0%Si D. Backside Metallization: None

Metal1 = 0.5 microns (as drawn) E. Minimum Metal Width: F. Minimum Metal Spacing: Metal1 = 0.45 microns (as drawn)

G. Bondpad Dimensions:

H. Isolation Dielectric: SiO₂ I. Die Separation Method: Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts: Don Lipps (Manager, Reliability Engineering)

Bryan Preeshl (Vice President of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% for all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppmD. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 230 \times 2}$$
 (Chi square value for MTTF upper limit) (where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV) $\lambda = 4.78 \times 10^{-9}$

% = 4.78 F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maximintegrated.com/qa/reliability/monitor. Cumulative monitor data for the M5 Process results in a FIT Rate of 0.21 @ 25C and 3.61 @ 55C (0.8 eV, 60% UCL).

B. E.S.D. and Latch-Up Testing (ESD lot N8DDBQ002E D/C 9924, Latch-Up lot N8DDBQ002J)

The RS78-3 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250mA.



Table 1Reliability Evaluation Test Results

MAX3183EEUK+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test	(Note 1)				
	Ta = 135°C	DC Parameters	80	0	N8DDBQ002E, D/C 9924
	Biased	& functionality	80	0	N8DBBQ002E, D/C 9924
	Time = 192 hrs.	•	70	0	N8DAAN001A, D/C 9907
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Note 1: Life Test Data may represent plastic DIP qualification lots.